



POWER-INTERFACE SWITCHES
FOR SERIAL PCMCIA CONTROLLERS

### **FEATURES**

- Single-Slot Switch: TPS2220B
- Fast Current Limit Response Time
- Fully Integrated VCC and VPP Switching for 3.3 V, 5 V, and 12 V
- Meets Current PC Card™ Standards
- V<sub>pp</sub> Output Selection Independent of V<sub>CC</sub>
- 12-V and 5-V Supplies Can Be Disabled
- TTL-Logic Compatible Inputs
- Short-Circuit and Thermal Protection
- 24-Pin HTSSOP and 24-Pin SSOP
- 140-µA (Typical) Quiescent Current from 3.3-V Input
- Break-Before-Make Switching

- Power-On Reset
- -40°C to 85°C Operating Ambient Temperature Range

### **APPLICATIONS**

- Notebook and Desktop Computers
- Bar Code Scanners
- Digital Cameras
- Set-Top Boxes
- PDAs

# **DESCRIPTION**

The TPS2220B power-interface switch provides an integrated power-management solution for single Card sockets. The device allows the controlled distribution of 3.3 V, 5 V, and 12 V to one card slot. The current-limiting and thermal-protection features eliminate the need for fuses. Current-limit reporting helps the user isolate a system fault. The switch  $r_{DS(on)}$  and current-limit values have been set for the peak and average current requirements stated in the PC Card specification, and optimized for cost.

Like the TPS2220A this device supports independent VPP/VCC switching. The TPS2220B is pin compatible with the TPA2220A execept for pin 20 of the TPS2220B which has no connection.

#### **AVAILABLE OPTIONS**

	PACKA	AGED DEVICE
T <sub>A</sub>	PLASTIC SMALL OUTLINE (DB-24) <sup>(1)</sup>	PowerPAD™ PLASTIC SMALL OUTLINE (PWP-24) <sup>(1)</sup>
-40°C to 85°C	TPS2220BDB	TPS2220BPWP

(1) The DB and PWP packages are also available taped and reeled. Add R suffix to device type (e.g., TPS2220BPWPR) for taped and reeled.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

PC Card is a trademark of PCMCIA (Personal Computer Memory Card International Association).





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# **ORDERING INFORMATION**

T <sub>A</sub>	SSOP(DB) <sup>(1)</sup>	STATUS	HTSSOP (PWP)(1)	STATUS
-40°C to 85°C	TPS2220BDB	Active	TPS2220BPWP	Active

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

# **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)(1)

			TPA2220B	
		V <sub>I(3.3V)</sub>	-0.3 V to 5.5 V	
$V_{I}$	Input voltage range for card power	V <sub>I(5V)</sub>	-0.3 V to 5.5 V	
		V <sub>I(12V)</sub>	-0.3 V to 14 V	
	Logic input/output voltage		-0.3 V to 6 V	
.,	Output valtage	V <sub>O(AVCC)</sub>	-0.3 V to 6 V	
Vo	Output voltage	V <sub>O(AVPP)</sub>	-0.3 V to 14 V	
	Continuous total power dissipation	See Dissipation Rating Table		
	Output ourset	I <sub>O(AVCC)</sub>	Internally Limited	
I <sub>O</sub>	Output current	I <sub>O(AVPP)</sub>	Internally Limited	
TJ	Operating virtual junction temperature range		-40°C to 100°C	
T <sub>stg</sub>	Storage temperature range	Storage temperature range		
	Lead temperature 1,6 mm (1/16 inch) from ca	260°C		
	OC sink current	10 mA		

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# **DISSIPATION RATING TABLE**

PAC	KAGE <sup>(1)</sup>	T <sub>A</sub> ≤ 25°C POWER RATING	^		T <sub>A</sub> = 85°C POWER RATING
DB	24	890 mW	8.9 mW/°C	489 mW	356 mW
PWP	24	3322 mW	33.22 mW/°C	1827 mW	1329 mW

(1) These devices are mounted on aa JEDEC low-k board (2-oz. traces on surface).



# RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
	Input voltage, V <sub>I(3.3V)</sub> is required for all circuit	V <sub>I(3.3V)</sub> <sup>(1)</sup>	3	3.6	
	operations. 5V and 12V are only required for	V <sub>I(5V)</sub>	3	5.5	V
	their respective functions.	V <sub>I(12V)</sub>	7	13.5	
	Output ourrent	$I_{O(AVCC)}$ at $T_J = 100^{\circ}C$		1	Α
IO	Output current	$I_{O(AVPP)}$ at $T_J = 100^{\circ}C$		100	mA
f <sub>(clock)</sub>	Clock frequency			2.5	MHz
		Data	200		
	Pulse duration	Latch	250		ns
t <sub>w</sub>	Pulse duration	Clock	100		115
		Reset	100		
t <sub>h</sub>	Data-to-clock hold time (see Figure 2)		100		ns
t <sub>su</sub>	Data-to-clock setup time (see Figure 2)		100		ns
t <sub>d(latch)</sub>	Latch delay time (see Figure 2)		100		ns
t <sub>d(clock)</sub>	Clock delay time (see Figure 2)	Clock delay time (see Figure 2)			
$T_{J}$	Operating virtual junction temperature (maximu	m to be calculated at worst case P <sub>D</sub> at 85°C ambient)	-40	100	°C

<sup>(1)</sup> It is understood that for  $V_{I(3.3V)} < 3 \text{ V}$ , voltages within the absolute maximum ratings applied to pin 5V or pin 12V do not damage the IC.

# **ELECTRICAL CHARACTERISTICS**

 $T_1 = 25^{\circ}$ C,  $V_{1/5}$ V = 5 V,  $V_{1/3}$ V = 3.3 V,  $V_{1/2}$ V = 12 V, all outputs unloaded (unless otherwise noted)

PARAMETER				TEST CONDITIONS(1)		MIN	TYP	MAX	UNIT
POWER	SWITCH								
		0.01/1.01/00		I <sub>O</sub> = 750 mA each		85	110		
		3.3V to AVCC		I <sub>O</sub> = 750 mA each, T <sub>J</sub> = 100°C			110	140	
		5)// A)/OO		I <sub>O</sub> = 500 mA each			95	130	mΩ
_	Static drain-source	5V to AVCC		I <sub>O</sub> = 500 mA each, T <sub>J</sub> = 100°C			120	160	
r <sub>DS(on)</sub>	on-state resistance	2 2)/ 07 5)/ 40 4)/D	ıD.	I <sub>O</sub> = 50 mA each			0.8	1	
		3.3V or 5V to AVP	P	$I_O = 50$ mA each, $T_J = 100$ °C			1	1.3	Ω
		12\/ to \/\/DD		I <sub>O</sub> = 50 mA each			2	2.5	52
		12V to AVPP		$I_O = 50$ mA each, $T_J = 100$ °C			2.5	3.4	
	Output discharge	Discharge at AVCC		I <sub>O(disc)</sub> = 1 mA		0.5	0.7	1	kΩ
	resistance	Discharge at AVPI	Р	I <sub>O(disc)</sub> = 1 mA		0.2	0.4	0.5	K22
			Limit (steady-state value), output	I <sub>OS(AVCC)</sub>	1	1.4	2	Α	
		Short-circuit output current		powered into a short circuit	I <sub>OS(AVPP)</sub>	120	200	300	mA
los	Short-circuit output cu			Limit (steady-state value), output	I <sub>OS(AVCC)</sub>	1	1.4	2	Α
				powered into a short circuit, T <sub>J</sub> = 100°C	I <sub>OS(AVPP)</sub>	120	200	300	mA
т	Thermal shutdown	Thermal trip point		Rising temperature			135		°C
TJ	temperature	Hysteresis					10		C
	Current-limit response	timo(2)(3)		5V to AVCC = 5 V, with 100-m $\Omega$ short to GND			10		
	Current-limit response	ume (=) (e)		5V to AVPP = 5 V, with 100-m $\Omega$ short to GND			3		μs
			I <sub>I(3.3V)</sub>				140	200	
		Normal operation	I <sub>I(5V)</sub>	V <sub>O</sub> (AVCC) = V <sub>O</sub> (AVPP) = 3.3 V and also for RESET = 0 V			8	12	
I	Input current, quiesc- ent	put current, quiesc-	$I_{I(12V)}$				100	180	
			I <sub>I(3.3V)</sub>				0.3	2	μA
		Shutdown mode	I <sub>I(5V)</sub>	$V_O(AVCC) = V_O(AVPP) = Hi-Z$			0.1	2	
		I <sub>I(12V)</sub>					0.3	2	

<sup>(1)</sup> Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

Specified by design; not tested in production. From application of short to 110% of final current limit.



# **ELECTRICAL CHARACTERISTICS (continued)**

 $T_J = 25$ °C,  $V_{I(5V)} = 5$  V,  $V_{I(3.3V)} = 3.3$  V,  $V_{I(12V)} = 12$  V, all outputs unloaded (unless otherwise noted)

	PARAM	ETER	TEST CONDITIONS(1)		MIN	TYP	MAX	UNIT
							10	·
	Leakage current,	01 11	$V_{O(AVCC)} = 5 \text{ V}, V_{I(5V)} = V_{I(12V)} = 0 \text{ V}$	T <sub>J</sub> = 100°C			50	
I <sub>lkg</sub>	output off state	Shutdown mode					10	μΑ
			$V_{O(AVPP)} = 12 \text{ V}, V_{I(5V)} = V_{I(12V)} = 0 \text{ V}$	T <sub>J</sub> = 100°C			50	1
LOGIC S	ECTION (CLOCK, DAT	A, LATCH, RESET, SHDI	v, oc)					
		(4)	RESET = 5.5 V		-1		1	1
		I <sub>I(/RESET)</sub> (4)	RESET = 0 V		-30	-20	-10	Ī
		. (4)	<u>SHDN</u> = 5.5 V		-1		1	Ī
I <sub>I</sub>	Input current, logic	I <sub>I(/SHDN)</sub> <sup>(4)</sup>	SHDN = 0 V		-50		-3	μA
		I <sub>I(LATCH)</sub> <sup>(4)</sup>	LATCH = 5.5 V			50	1	
			LATCH = 0 V		-1		1	
		I <sub>I(CLOCK, DATA)</sub>	0 V to 5.5 V		-1		1	1
V <sub>IH</sub>	High-level input voltag				2			V
V <sub>IL</sub>	Low-level input voltage	e, logic					0.8	V
V <sub>O(sat)</sub>	Output saturation volta	age at OC	I <sub>O</sub> = 2 mA			0.14	0.4	V
I <sub>lkg</sub>	Leakage current at OC	5	V <sub>O(/OC)</sub> = 5.5 V			0	1	μA
UVLO AN	ND POR (POWER-ON R	RESET)						
V <sub>I(3.3V)</sub>	Input voltage at 3.3V p	oin, UVLO	3.3-V level below which all switches are	Hi-Z	2.4	2.7	2.9	V
V <sub>hys(3.3V)</sub>	UVLO hysteresis volta	age at VA <sup>(5)</sup>				100		mV
V <sub>I(5V)</sub>	Input voltage at 5V pir	n, UVLO	5-V level below which only 5V switches	are Hi-Z	2.3	2.5	2.8	V
V <sub>hys(5V)</sub>	UVLO hysteresis volta	age at 5V <sup>(5)</sup>	Delay from voltage hit (step from 3 V to Hi-Z control (90% V <sub>G</sub> to GND)	2.3 V) to		100		mV
t <sub>df</sub>	Delay time for falling r	esponse, UVLO(5)				4		μs
V <sub>I(POR)</sub>	Input voltage, power-o	on reset <sup>(5)</sup>	3.3-V voltage below which POR is asser RESET internally with all line switches o discharge switches closed.				1.7	V

 <sup>(4)</sup> LATCH has low-current pulldown. RESET and SHDN have low-current pullup.
 (5) Specified by design; not tested in production.



# **SWITCHING CHARACTERISTICS**

 $V_{CC} = 5 \text{ V}, \text{ T}_{A} = 25 ^{\circ}\text{C}, \text{ V}_{I(3.3 \text{V})} = 3.3 \text{ V}, \text{ V}_{I(5 \text{V})} = 5 \text{ V}, \text{ V}_{I(12)} = 12 \text{ V}, \text{ all outputs unloaded (unless otherwise noted)}$ 

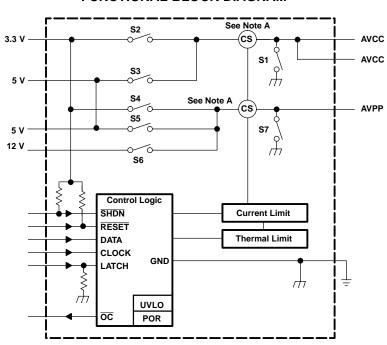
	PARAMETER (1)	LOAD CONDITION	TEST CONDITIONS	(2)	MIN TYP	MAX	UNIT
		$C_{L(AVCC)} = 0.1 \mu F, C_{L(AVPP)} = 0.1 \mu F,$	$V_{O(AVCC)} = 5 V$		0.9		
	t <sub>f</sub> Output rise times <sup>(3)</sup> t <sub>f</sub> Output fall times <sup>(3)</sup>	$I_{O(AVCC)} = 0 A, I_{O(AVPP)} = 0 A$	$V_{O(AVPP)} = 12 \text{ V}$		0.26		ms
۱r		$C_{L(AVCC)} = 150 \mu F, C_{L(AVPP)} = 10 \mu F,$	$V_{O(AVCC)} = 5 V$		1.1		1115
		$I_{O(AVCC)} = 0.75 \text{ A}, I_{O(AVPP)} = 50 \text{ mA}$	$V_{O(AVPP)} = 12 \text{ V}$		0.6		
		$C_{L(AVCC)} = 0.1 \ \mu F, \ C_{L(AVPP)} = 0.1 \ \mu F,$	V <sub>O(AVCC)</sub> = 5 V, Discharge switches ON		0.5		
t <sub>f</sub>	Output fall times (3)	$I_{O(AVCC)} = 0 A, I_{O(AVPP)} = 0 A$	V <sub>O(AVPP)</sub> = 12 V, Discharge switches ON		0.2		ms
		$C_{L(AVCC)} = 150 \mu F, C_{L(AVPP)} = 10 \mu F,$	$V_{O(AVCC)} = 5 V$		2.35		•
		$I_{O(AVCC)} = 0.75 \text{ A}, I_{O(AVPP)} = 50 \text{ mA}$			3.9		•
			Latch↑ to AVPP (12V)	t <sub>pdon</sub>	2		
			Laiciii to AVPP (12V)	t <sub>pdoff</sub>	0.62		
		$C_{L(AVCC)} = 0.1 \ \mu F, \ C_{L(AVPP)} = 0.1 \ \mu F,$ $I_{O(AVCC)} = 0 \ A, \ I_{O(AVPP)} = 0 \ A$	Latch <sup>↑</sup> to AVPP (5V)	t <sub>pdon</sub>	0.77		ms
				t <sub>pdoff</sub>	0.51		
			Latch <sup>↑</sup> to AVPP (3.3V)	t <sub>pdon</sub>	0.75		
				t <sub>pdoff</sub>	0.52		
			Latch↑ to AVCC (5V)	t <sub>pdon</sub>	0.3		
			t <sub>po</sub>		2.5		
			Latch↑ to AVCC (3.3V)	t <sub>pdon</sub>	0.3		
	Propagation delay		taicii io AVCC (3.3V)		2.8		
t <sub>pd</sub>	times (3)		Latch↑ to AVPP (12V)	t <sub>pdon</sub>	2.2		
			Laich to AVPP (12V)	t <sub>pdoff</sub>	0.8		
			1 -+	t <sub>pdon</sub>	8.0		1
			Latch↑ to AVPP (5V)	t <sub>pdoff</sub>	0.6		•
		$C_{L(AVCC)} = 150 \mu F, C_{L(AVPP)} = 10 \mu F,$	Letch↑ to A\/DD (2.2\/)	t <sub>pdon</sub>	0.8		ms
		$I_{O(AVCC)} = 0.75 \text{ A}, I_{O(AVPP)} = 50 \text{ mA}$	Latch↑ to AVPP (3.3V)	t <sub>pdoff</sub>	0.6		
			Latab to AVCC (EV)	t <sub>pdon</sub>	0.6		
			Latch↑ to AVCC (5V)	t <sub>pdoff</sub>	2.5		
			1 . 1 1 . AV (00 (0 5) 0	t <sub>pdon</sub>	0.5		
			Latch↑ to AVCC (3.3V) t <sub>pdof</sub>		2.6		į l

<sup>(1)</sup> Refer to Parameter Measurement Information in Figure 1.

 <sup>(2)</sup> No card inserted, assumes a 0.1-µF output capacitor (see Figure 1).
 (3) Specified by design; not tested in production.



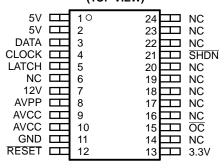
### **FUNCTIONAL BLOCK DIAGRAM**



NOTES: A. Current sense

# **PIN ASSIGNMENTS**

### TPS2220B DB OR PWP PACKAGE (TOP VIEW)



NC - No internal connection



# **PIN ASSIGNMENTS (continued)**

# **Terminal Functions**

TER	MINAL		
NAME	MF NO.		DESCRIPTION
NAME	TPS2220B		
3.3V	13	I	3.3-V input for card power and chip power
5V	1, 2	I	5-V input for card power
12V	7	I	12-V input for card power (AVPP).
AVCC	9, 10	0	Switched output that delivers 3.3 V, 5 V, ground or high impedance to card
AVPP	8	0	Switched output that delivers 3.3 V, 5 V, 12 V, ground or high impedance to card
GND	11		Ground
<del>OC</del>	15	0	Open-drain overcurrent reporting output that goes low when an overcurrent condition exists. An external pullup is required.
SHDN	21	I	Hi-Z (open) all switches. Identical function to serial D8. Asynchronous active-low command, internal pullup
RESET	12	1	Logic-level RESET input active low. Asynchronous active-low command, internal pullup
CLOCK	4	I	Logic-level clock for serial data word
DATA	3	I	Logic-level serial data word
LATCH	5	ı	Logic-level latch for serial data word, internal pulldown
NC	6, 14, 16, 17, 18, 19, 20, 22, 23, 24		No internal connection



# PARAMETER MEASUREMENT INFORMATION

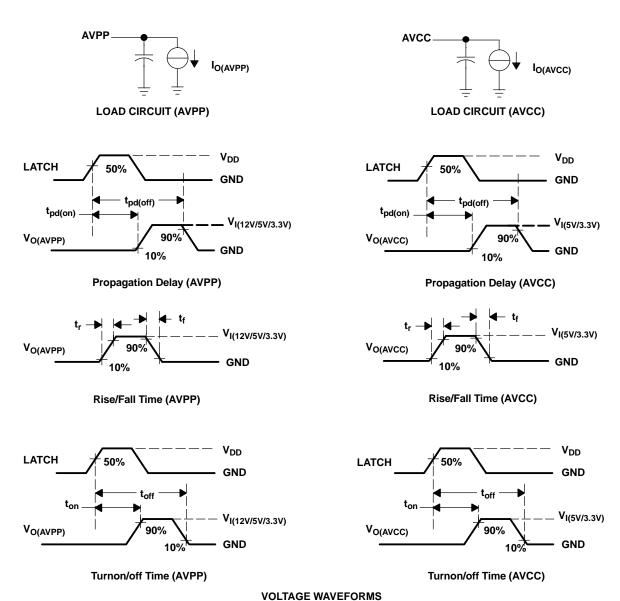
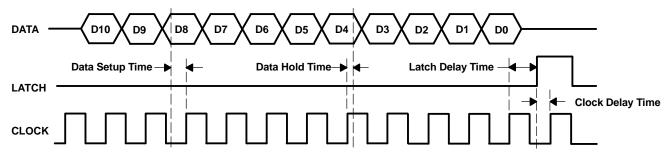


Figure 1. Test Circuits and Voltage Waveforms



NOTE: Data is clocked in on the positive edge of the clock. The positive edge of the latch signal should occur before the next positive edge of the clock. For definition of D0 to D10, see the control logic table.

Figure 2. Serial-Interface Timing for TPS2220B



# **Table of Graphs**

		FIGURE
Short-circuit response, short applied to powered-on 5-V AVCC-switch output	vs Time	3
Short-circuit response, short applied to powered-on 12-V AVPP-switch output	vs Time	4
OC response with ramped overcurrent-limit load on 5-V AVCC-switch output	vs Time	5
OC response with ramped overcurrent-limit load on 12-V AVPP-switch output	vs Time	6
AVCC Turnon propagation delay time ( $C_L = 150 \mu F$ )	vs Junction temperature	7
AVCC Turnoff propagation delay time (C <sub>L</sub> = 150 μF)	vs Junction temperature	8
AVPP Turnon propagation delay time ( $C_L = 10 \mu F$ )	vs Junction temperature	9
AVPP Turnoff propagation delay time ( $C_L = 10 \mu F$ )	vs Junction temperature	10
AVCC Turnon propagation delay time (T <sub>J</sub> = 25°C)	vs Load capacitance	11
AVCC Turnoff propagation delay time (T <sub>J</sub> = 25°C)	vs Load capacitance	12
AVPP Turnon propagation delay time (T <sub>J</sub> = 25°C)	vs Load capacitance	13
AVPP Turnoff propagation delay time (T <sub>J</sub> = 25°C)	vs Load capacitance	14
AVCC Rise time ( $C_L = 150 \mu F$ )	vs Junction temperature	15
AVCC Fall time ( $C_L = 150 \mu F$ )	vs Junction temperature	16
AVPP Rise time ( $C_L = 10 \mu F$ )	vs Junction temperature	17
AVPP Fall time ( $C_L = 10 \mu F$ )	vs Junction temperature	18
AVCC Rise time (T <sub>J</sub> = 25°C)	vs Load capacitance	19
AVCC Fall time (T <sub>J</sub> = 25°C)	vs Load capacitance	20
AVPP Rise time (T <sub>J</sub> = 25°C)	vs Load capacitance	21
AVPP Fall time ( $T_J = 25^{\circ}C$ )	vs Load capacitance	22



### SHORT-CIRCIUT RESPONSE, SHORT APPLIED TO POWERED-ON 5-V AVCC-SWITCH OUTPUT

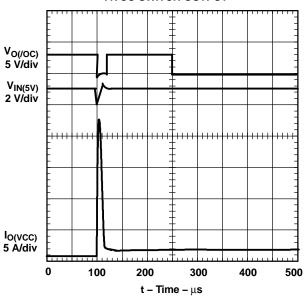


Figure 3.

### SHORT-CIRCIUT RESPONSE, SHORT APPLIED TO POWERED-ON 12-V AVPP-SWITCH OUTPUT

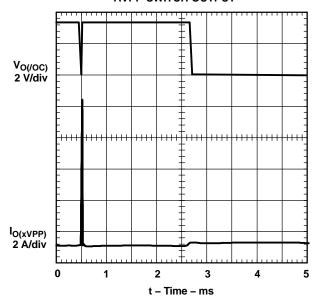


Figure 4.

### OC RESPONSE WITH RAMPED OVERCURRENT-LIMIT LOAD ON 5-V AVCC-SWITCH OUTPUT

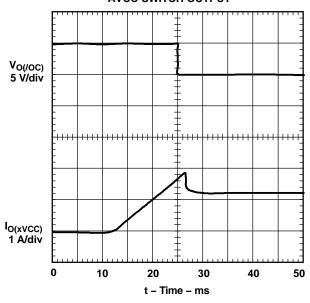


Figure 5.

### OC RESPONSE WITH RAMPED OVERCURRENT-LIMIT LOAD ON 12-V AVPP-SWITCH OUTPUT

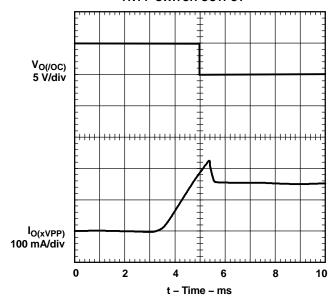
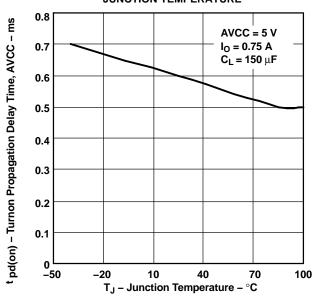


Figure 6.







# Figure 7.

# TURNON PROPAGATION DELAY TIME, AVPP vs JUNCTION TEMPERATURE

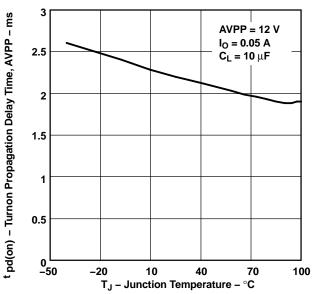


Figure 9.

# TURNOFF PROPAGATION DELAY TIME, AVCC vs JUNCTION TEMPERATURE

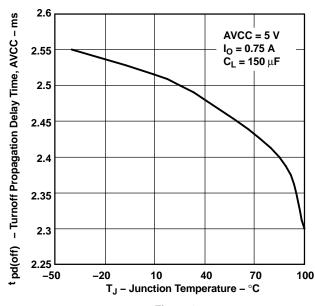


Figure 8.

# TURNON PROPAGATION DELAY TIME, AVPP vs JUNCTION TEMPERATURE

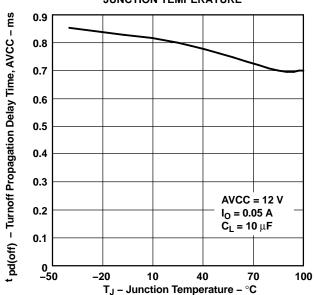
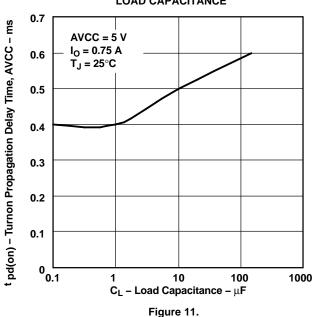


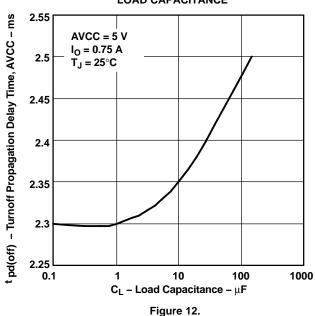
Figure 10.



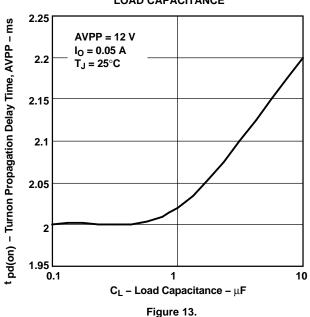
# TURNON PROPAGATION DELAY TIME, AVCC vs LOAD CAPACITANCE



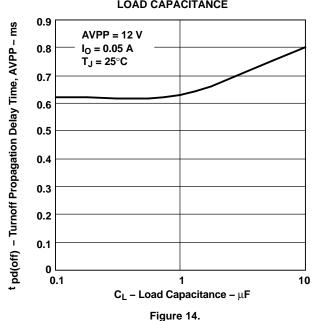
# TURNON PROPAGATION DELAY TIME, AVCC vs LOAD CAPACITANCE



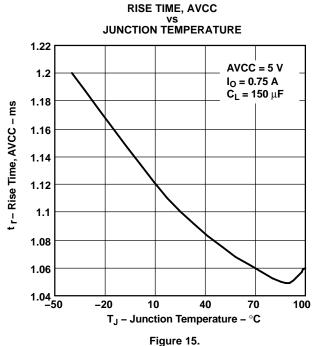
# TURNON PROPAGATION DELAY TIME, AVPP VS LOAD CAPACITANCE



### TURNON PROPAGATION DELAY TIME, AVPP VS LOAD CAPACITANCE









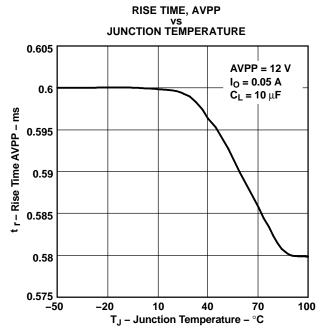


Figure 17.



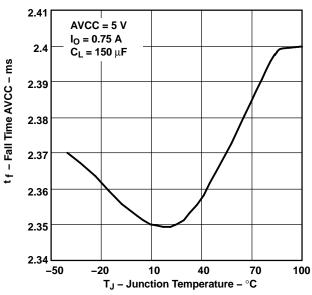


Figure 16.

# FALL TIME, AVPP vs JUNCTION TEMPERATURE

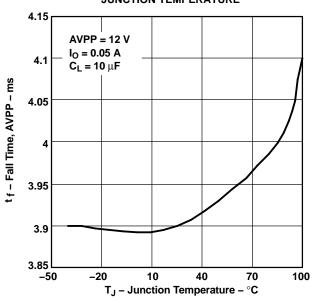
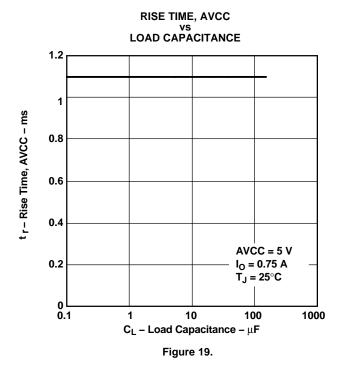
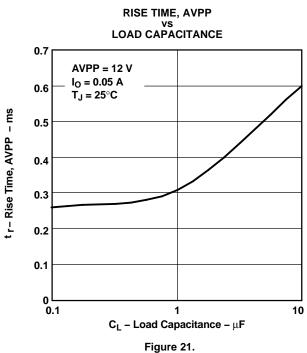
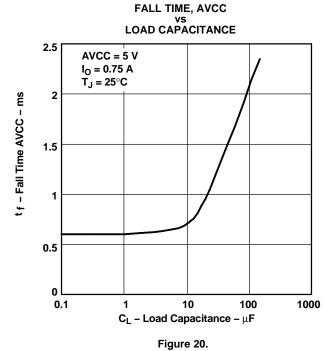


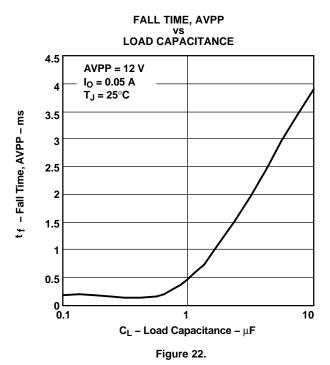
Figure 18.











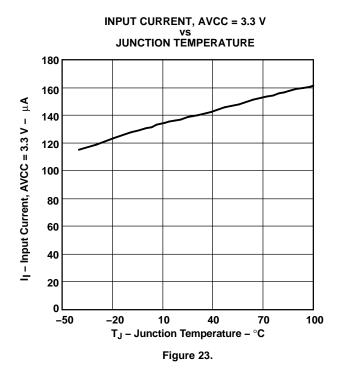


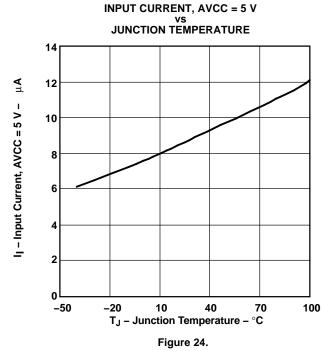
# **TYPICAL CHARACTERISTICS**

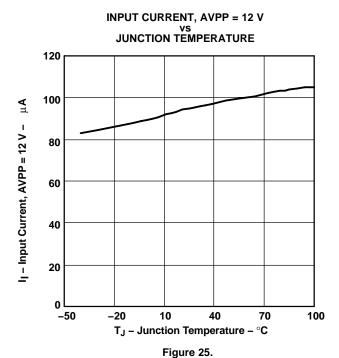
# **Table of Graphs**

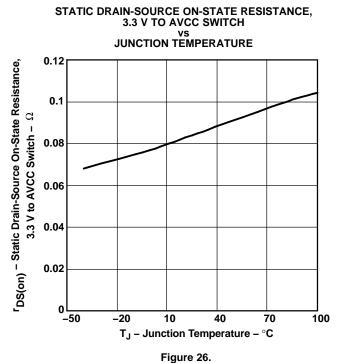
			FIGURE			
	Input current, AVCC = 3.3 V		23			
ı	Input current, AVCC = 5 V	vs Junction temperature	24			
	Input current, AVPP = 12 V					
	Static drain-source on-state resistance, 3.3 V to AVCC switch		26			
DS(on)	Static drain-source on-state resistance, 5 V to AVCC switch	vs Junction temperature	27			
` ′	Static drain-source on-state resistance, 12 V to AVPP switch	te resistance, 12 V to AVPP switch				
	AVCC switch voltage drop, 3.3-V input		29			
/ <sub>0</sub>	AVCC switch voltage drop, 5-V input	vs Load current	30			
	AVPP switch voltage drop, 12-V input		31			
	Short-circuit current limit, 3.3 V to AVCC		32			
os	Short-circuit current limit, 5 V to AVCC	vs Junction temperature	33			
	Short-circuit current limit, 12 V to AVPP		34			















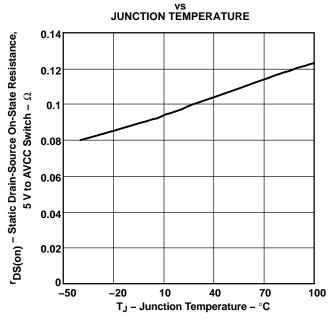


Figure 27.

# STATIC DRAIN-SOURCE ON-STATE RESISTANCE, 12 V TO AVPP SWITCH

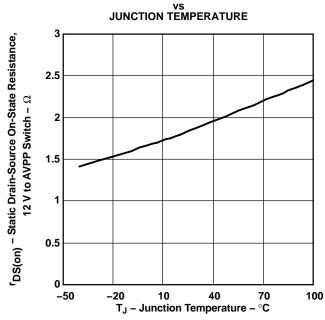


Figure 28.

# AVCC SWITCH VOLTAGE DROP, 3.3-V INPUT vs

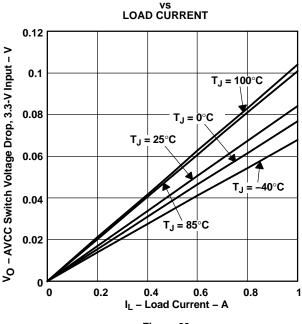


Figure 29.

#### AVCC SWITCH VOLTAGE DROP, 5-V INPUT vs LOAD CURRENT

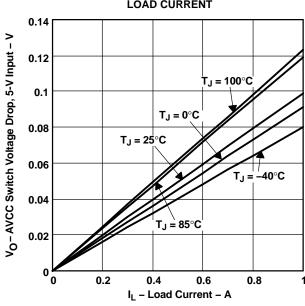
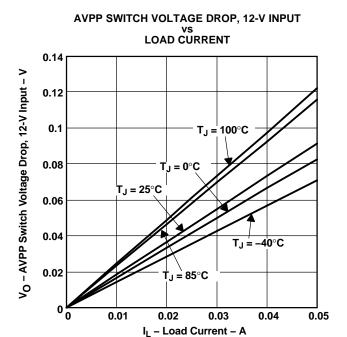


Figure 30.





### Figure 31.

SHORT-CIRCUIT CURRENT LIMIT, 5 V TO AVCC

# vs JUNCTION TEMPERATURE 1.435 IOS - Short-Circuit Current Limit, 5 V to AVCC - A 1.43 1.425 1.42 1.415 1.41 1.405 1.4 1.395 1.39 1.385 **-50** -20 10 40 70 100 T<sub>J</sub> - Junction Temperature - °C

Figure 33.

SHORT-CIRCUIT CURRENT LIMIT, 3.3 V TO AVCC vs
JUNCTION TEMPERATURE

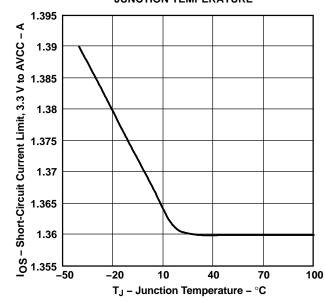


Figure 32.

# SHORT-CIRCUIT CURRENT LIMIT, 12 V TO AVPP vs JUNCTION TEMPERATURE

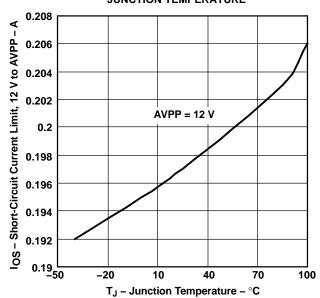


Figure 34.



### **APPLICATION INFORMATION**

### **OVERVIEW**

PC Cards were initially introduced as a means to add flash memory to portable computers. The idea of add-in cards quickly took hold, and modems, wireless LANs, global positioning satellite system (GPS), multimedia, and hard-disk versions were soon available. As the number of PC Card applications grew, the engineering community quickly recognized the need for a standard to ensure compatibility across platforms. Therefore, the PCMCIA (Personal Computer Memory Card International Association) was established, comprising members from leading computer, software, PC Card, and semiconductor manufacturers. One key goal was to realize the plug-and-play concept, so that cards and hosts from different vendors would be transparently compatible.

# PC CARD POWER SPECIFICATION

System compatibility also means power compatibility. The most current set of specifications (PC Card Standard) set forth by the PCMCIA committee states that power is to be transferred between the host and the card through eight of the 68 terminals of the PC Card connector. This power interface consists of two  $V_{CC}$ , two  $V_{pp}$ , and four ground terminals. Multiple  $V_{CC}$  and ground terminals minimize connector-terminal and line resistance. The two  $V_{pp}$  terminals were originally specified as separate signals, but are normally tied together in the host to form a single node to minimize voltage losses. Card primary power is supplied through the  $V_{CC}$  terminals; flash-memory programming and erase voltage is supplied through the  $V_{pp}$  terminals. Cardbus cards of today typically do not use 12 V, which is now more of an optional requirement in the host.

# **DESIGNING FOR VOLTAGE REGULATION**

The current PCMCIA specification for output voltage regulation,  $V_{O(reg)}$ , of the 5-V output is 5% (250 mV). In a typical PC power-system design, the power supply has an output-voltage regulation,  $V_{PS(reg)}$ , of 2% (100 mV). Also, a voltage drop from the power supply to the PC Card results from resistive losses,  $V_{PCB}$ , in the PCB traces and the PCMCIA connector. A typical design would limit the total of these resistive losses to less than 1% (50 mV) of the output voltage. Therefore, the allowable voltage drop,  $V_{DS}$ , for the TPS2220B would be the PCMCIA voltage regulation less the power supply regulation and less the PCB and connector resistive drops:

$$V_{DS} \times V_{O(reg)} - V_{PS(reg)} - V_{PCB}$$

Typically, this would leave 100 mV for the allowable voltage drop across the 5-V switch. The specification for output voltage regulation of the 3.3-V output is 300 mV; therefore, using the same equation by deducting the voltage drop percentages (2%) for power-supply regulation and PCB resistive loss (1%), the allowable voltage drop for the 3.3-V switch is 200 mV. The voltage drop is the output current multiplied by the switch resistance of the device. Therefore, the maximum output current, I<sub>O</sub> max, that can be delivered to the PC Card in regulation is the allowable voltage drop across the IC, divided by the output-switch resistance.

$$I_{O}^{max} \times \frac{V_{DS}}{r_{DS(on)}}$$

The AVCC outputs have been designed to deliver the peak and average currents defined by the PC Card specification within regulation over the operating temperature range. The AVPP outputs of the device have been designed to deliver 100 mA continuously.

# OVERCURRENT AND OVERTEMPERATURE PROTECTION

PC Cards are inherently subject to damage that can result from mishandling. Host systems require protection against short-circuited cards that can lead to power-supply or PCB trace damage. Even extremely robust systems can undergo rapid battery discharge into a damaged PC Card, resulting in the sudden and unacceptable loss of system power. In comparison, the reliability of fused systems is poor because blown fuses require troubleshooting and repair, usually by the manufacturer.

The TPS2220B takes a two-pronged approach to overcurrent protection, which is designed to activate if an output is shorted or when an overcurrent condition is present when switches are powered up. First, instead of fuses, sense FETs monitor each of the AVCC and AVPP power outputs. Unlike sense resistors or polyfuses,



# **APPLICATION INFORMATION (continued)**

these FETs do not add to the series resistance of the switch; therefore, voltage and power losses are reduced. Overcurrent sensing is applied to each output separately. Excessive current generates an error signal that limits the output current of only the affected output, preventing damage to the host. Each AVCC output overcurrent limits from 1 A to 2.2 A, typically around 1.6 A; the AVPP outputs limit from 100 mA to 250 mA, typically around 200 mA.

Second, when an overcurrent condition is detected, the TPS2220B asserts an active low  $\overline{OC}$  signal that can be monitored by the microprocessor or controller to initiate diagnostics and/or send the user a warning message. If an overcurrent condition persists, causing the IC to exceed its maximum junction temperature, thermal-protection circuitry activates, shutting down all power outputs until the device cools to within a safe operating region, which is ensured by a thermal shutdown hysteresis. Thermal limiting prevents destruction of the IC from overheating beyond the package power-dissipation ratings.

During power up, the devices control the rise times of the AVCC and AVPP outputs and limit the inrush current into a large load capacitance, faulty card, or connector.

# 12-V SUPPLY NOT REQUIRED

Some PC Card switches use the externally supplied 12 V to power gate drive and other chip functions, which requires that power be present at all times. The TPS2220B offers considerable power savings by using an internal charge pump to generate the required higher gate drive voltages from the 3.3-V input. Therefore, the external 12-V supply can be disabled except when needed by the PC Card in the slot, thereby extending battery lifetime. A special feature in the 12-V circuitry actually helps to reduce the supply current demanded from the 3.3-V input. When 12 V is supplied and requested at the VPP output, a voltage selection circuit draws the charge-pump drive current for the 12-V FETs from the 12-V input. This selection is automatic and effectively reduces demand fluctuations on the normal 3.3-V VCC rail. For proper operation of this feature, a minimum 3.3-V input capacitance of 4.7  $\mu$ F is recommended, and a minimum 12-V input ramp-up rate of 12 V/50 ms (240 V/s) is required. Additional power savings are realized during a software shutdown in which quiescent current drops to a maximum of 1  $\mu$ A.

### **VOLTAGE-TRANSITIONING REQUIREMENT**

PC Cards, like portables, are migrating from 5 V to 3.3 V to minimize power consumption, optimize board space, and increase logic speeds. The TPS2220B meets all combinations of power delivery as currently defined in the PCMCIA standard. The latest protocol accommodates mixed 3.3-V/5-V systems by first powering the card with 5 V, then polling it to determine its 3.3-V compatibility. The PCMCIA specification requires that the capacitors on 3.3-V-compatible cards be discharged to below 0.8 V before applying 3.3-V power. This action ensures that sensitive 3.3-V circuitry is not subjected to any residual 5-V charge and functions as a power reset. PC Card specification requires that  $V_{\rm CC}$  be discharged within 100 ms. PC Card resistance cannot be relied on to provide a discharge path for voltages stored on PC Card capacitance because of possible high-impedance isolation by power-management schemes. The devices include discharge transistors on all AVCC and AVPP outputs to meet the specification requirement.

# **SHUTDOWN MODE**

In the shutdown mode, which can be controlled by SHDN or bit D8 of the input serial DATA word, each of the AVCC and AVPP outputs is forced to a high-impedance state. In this mode, the chip quiescent current is reduced to 1 µA or less to conserve battery power.

### **POWER-SUPPLY CONSIDERATIONS**

The devices has multiple pins for 5-V power input and for the switched AVCC output. Any individual pin can conduct the rated input or output current. Unless all pins are connected in parallel, the series resistance is higher than that specified, resulting in increased voltage drops and power loss. It is recommended that all input and output power pins be paralleled for optimum operation.

To increase the noise immunity of the TPS2220B the power-supply inputs should be bypassed with at least a 4.7-µF electrolytic or tantalum capacitor paralleled by a 0.047-µF to 0.1-µF ceramic capacitor. It is strongly



# **APPLICATION INFORMATION (continued)**

recommended that the switched outputs be bypassed with a  $0.1-\mu F$  (or larger) ceramic capacitor; doing so improves the immunity of the IC to electrostatic discharge (ESD). Care should be taken to minimize the inductance of PCB traces between the devices and the load. High switching currents can produce large negative voltage transients, which forward biases substrate diodes, resulting in unpredictable performance. Similarly, no pin should be taken below -0.3 V.

# **RESET INPUT**

To ensure that cards are in a known state after power brownouts or system initialization, the PC Cards should be reset at the same time as the host by applying low-impedance paths from AVCC and AVPP terminals to ground. A low-impedance output state allows discharging of residual voltage remaining on PC Card filter capacitance, permitting the system (host and PC Cards) to be powered up concurrently. The active low  $\overline{RESET}$  input closes internal ground switches S1, S4, S7, and S11 with all other switches left open. The TPS2220B remains in the low-impedance output state until the signal is deasserted and further data is clocked in and latched. The input serial data cannot be latched during reset mode.  $\overline{RESET}$  is provided for direct compatibility with systems that use an active-low reset voltage supervisor. The  $\overline{RESET}$  pin has an internal 150-k $\Omega$  pullup resistor.

# **CALCULATING JUNCTION TEMPERATURE**

The switch resistance,  $r_{DS(on)}$ , is dependent on the junction temperature,  $T_J$ , of the die. The junction temperature is dependent on both  $r_{DS(on)}$  and the current through the switch. To calculate  $T_J$ , first find  $r_{DS(on)}$  from Figure 26 through Figure 28, using an initial temperature estimate about 30°C above ambient. Then, calculate the power dissipation for each switch, using the formula:

$$P_D + r_{DS(on)} \times I^2$$

Next, sum the power dissipation of all switches and calculate the junction temperature:

$$T_{J} = \left(\sum P_{D} \times R_{\theta JA}\right) + T_{A}$$

where:

 $R_{\theta,IA}$  is the inverse of the derating factor given in the dissipation rating table.

Compare the calculated junction temperature with the initial temperature estimate. If the temperatures are not within a few degrees of each other, recalculate using the calculated temperature as the initial estimate.

### LOGIC INPUTS AND OUTPUTS

The serial interface consists of the DATA, CLOCK, and LATCH leads. The data is clocked in on the positive edge of the clock (see Figure 2). The 11-bit (D0-D10) serial data word is loaded during the positive edge of the latch signal. The positive edge of the latch signal should occur before the next positive edge of the clock occurs.

The serial interface of the device is compatible with serial-interface PCMCIA controllers.

An overcurrent output ( $\overline{OC}$ ) is provided to indicate an overcurrent or overtemperature condition in any of the AVCC and AVPP outputs as previously discussed.



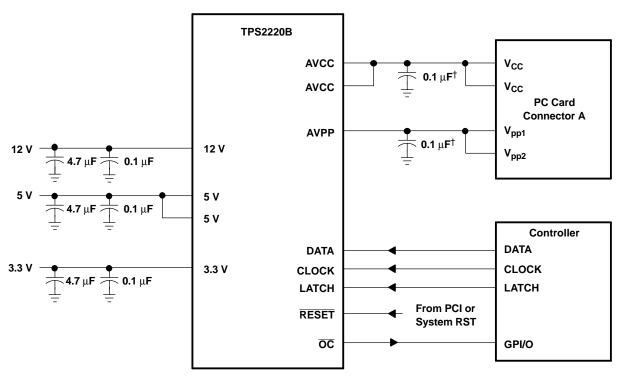
# **APPLICATION INFORMATION (continued)**

# **TPS2220B CONTROL LOGIC**

AVPP					AVCC			
AVPP CONTROL SIGNALS OUTPUT			AVCC CO	NTROL SIGNA	LS	OUTPUT		
D8 (SHDN)	D0	D1	D9	V_AVPP	D8 (SHDN)	D3	D2	V_AVCC
1	0	0	Х	0 V	1	0	0	0 V
1	0	1	0	3.3 V	1	0	1	3.3 V
1	0	1	1	5 V	1	1	0	5 V
1	1	0	Х	12 V	1	1	1	0 V
1	1	1	Х	Hi-Z	0	Х	Х	Hi-Z
0	Х	Х	Х	Hi-Z		•	•	

# **ESD PROTECTIONS (see Figure 35)**

All inputs and outputs of these devices incorporate ESD-protection circuitry designed to withstand a 2-kV human-body-model discharge as defined in MIL-STD-883C, Method 3015. The AVCC and AVPP outputs can be exposed to potentially higher discharges from the external environment through the PC Card connector. Bypassing the outputs with 0.1-µF capacitors protects the devices from discharges up to 10 kV.



 $<sup>^{\</sup>dagger}$  Maximum recommended output capacitance for AVCC is 220  $\mu$ F including card capacitance, and for AVPP is 10  $\mu$ F, without  $\overline{OC}$  glitch when switches are powered on.

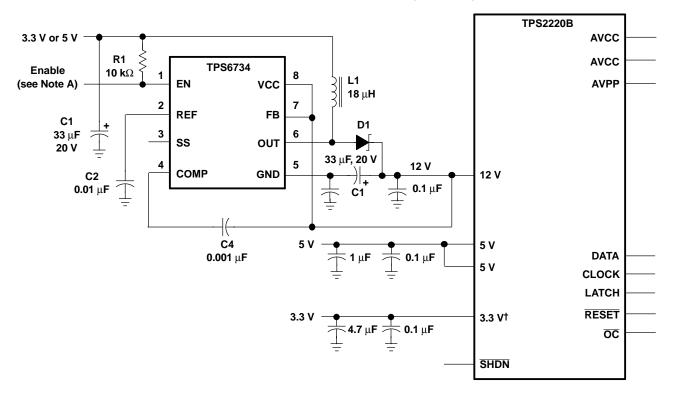
Figure 35. Detailed Interconnections and Capacitor Recommendations



### 12-V FLASH MEMORY SUPPLY

The TPS6734 is a fixed 12-V output boost converter capable of delivering 120 mA from inputs as low as 2.7 V. The device is pin-for-pin compatible with the MAX734 regulator and offers the following advantages: lower supply current, wider operating input-voltage range, and higher output currents. As shown in Figure 36, the only external components required are: an inductor, a Schottky rectifier, an output filter capacitor, an input filter capacitor, and a small capacitor for loop compensation. The entire converter occupies less than  $0.7 \text{ in}^2$  of PCB space when implemented with surface-mount components. An enable input is provided to shut the converter down and reduce the supply current to  $3 \mu \text{A}$  when 12 V is not needed.

The TPS6734 is a 170-kHz current-mode PWM (pulse-width modulation) controller with an n-channel MOSFET power switch. Gate drive for the switch is derived from the 12-V output after start-up to minimize the die area needed to realize the  $0.7-\Omega$  MOSFET and improve efficiency at input voltages below 5 V. Soft start is accomplished with the addition of one small capacitor. A 1.22-V reference, pin 2 of TPS6734, is brought out for external use. For additional information, see the TPS6734 data sheet (SLVS127).



NOTE A: The enable terminal can be tied to a general-purpose I/O terminal on the PCMCIA controller or tied high.

Figure 36. TPS2220B With TPS6734 12-V, 120-mA Supply





i.com 19-May-2005

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS2220BDB	ACTIVE	SSOP	DB	24	60	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS2220BDBG4	ACTIVE	SSOP	DB	24	60	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS2220BDBR	ACTIVE	SSOP	DB	24	2000	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS2220BDBRG4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2220BPWP	ACTIVE	HTSSOP	PWP	24	60	TBD	CU NIPDAU	Level-1-220C-UNLIM
TPS2220BPWPR	ACTIVE	HTSSOP	PWP	24	2000	TBD	CU NIPDAU	Level-1-220C-UNLIM

 $^{(1)}$  The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

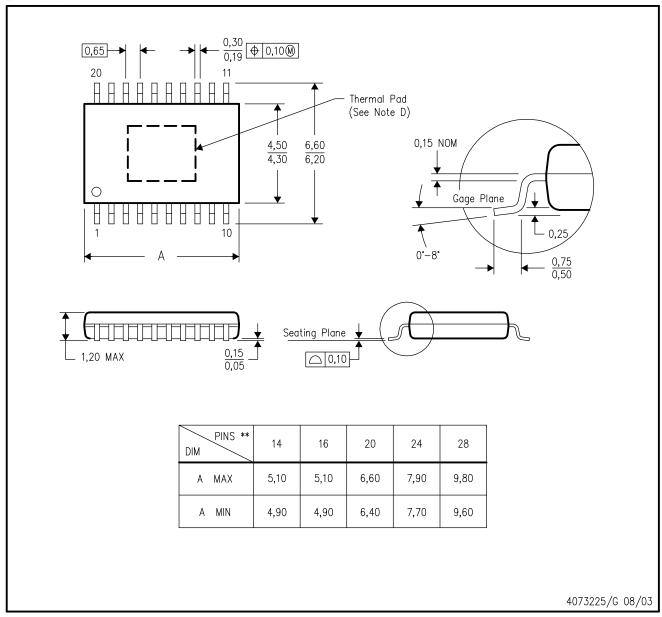
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# PWP (R-PDSO-G\*\*) PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

20 PIN SHOWN



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusions.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="https://www.ti.com">www.ti.com</a>.
- E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



# DB (R-PDSO-G\*\*)

# PLASTIC SMALL-OUTLINE

# **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2005, Texas Instruments Incorporated

Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from:

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com